TOSHIBA Intelligent Power Module Silicon N Channel IGBT

MIG150Q101H

High Power Switching Applications

Motor Control Applications

- Integrates inverter power & control circuits (IGBT drive units, protection units for over-current, under-voltage & over-temperature) in one package.
- The electrodes are isolated from case.
- High speed type IGBT : V_{CE} (sat) = 3.5 V (Max.)

 $t_{off} = 3.8 \ \mu s$ (Max.)

 $t_{rr} = 0.24 \ \mu s$ (Max.)

- Package Dimensions : TOSHIBA 2-121A1A
- Weight : 510 g

Equivalent Circuit



Maximum Ratings (T_j = 25°C)

Stage	Characteristic	Condition	Symbol	Ratings	Unit
Inverter	Supply voltage	P-N power terminal	V _{CC}	900	V
	Collector-emitter voltage	—	V _{CES}	1200	V
	Collector current	Tc = 25°C, DC	Ι _C	150	А
	Forward current	Tc = 25°C, DC	١ _F	150	А
	Collector power dissipation	Tc = 25°C	PC	1200	W
	Junction temperature	—	Тј	150	°C
Control	Control supply voltage	V _D -GND terminal	VD	20	V
	Input voltage	IN-GND terminal	VIN	20	V
	Fault output voltage	FO-GND (L) terminal	V _{FO}	20	V
	Fault output current	FO sink current	I _{FO}	14	mA
Module	Operating temperature	—	TC	-20 ~ +100	°C
	Storage temperature range	—	T _{stg}	-40 ~ +125	°C
	Isolation voltage	AC 1 minute	V _{ISO}	2500	V
	Screw torque	M6	—	3	N∙m

Electrical Characteristics (T_j = 25°C)

a. Inverter Stage

Characteristic	Symbol	Test Condition		Min	Тур.	Max	Unit
Collector cut-off current	lor	I_{CE} $V_{CE} = 1200 V$ $\frac{T_j}{T_j}$	T _j = 25°C	_	—	2	mA
	'CE		T _j = 125°C	—	-	40	
Collector emitter acturation voltage		V _D = 15 V, I _C = 150 A	T _j = 25°C	_	2.7	3.5	V
Conector-ennuer saturation voltage	V_{CE} (sat) $V_{\text{IN}} = 3 \text{ V} \rightarrow 0 \text{ V}$	$V_{IN} = 3 V \rightarrow 0 V$	T _j = 125°C	_	2.6	_	v
Forward voltage	V _F	IF = 150 A		_	2.0	2.5	V
	t _{on}	V_{CC} = 600 V, I _C = 150 A V _D = 15 V, V _{IN} = 3 V ↔ 0 V Inductive load		0.8	1.5	2.2	μs
	t _{c(on)}			_	0.5	1.0	
Switching time	t _{rr}			_	0.16	0.24	
	t _{off}		(Attached 1)	_	3.3	3.8	
	t _{c(off)}			_	0.4	0.8	

b. Control Stage (T_j = 25°C)

Characteristic		Symbol	Test Condition	Min	Тур.	Max	Unit
Control circuit current		ID	V _D = 15 V	_	20	30	mA
Input-on signal voltage		V _{IN (on)}	V _D = 15 V, I _C = 150 mA	0.9	1.1	1.3	V
Fault output current	Protection	I _{FO (on)}	- V _D = 15 V	8	10	12	mA
	Normal	IFO (off)		_	_	1	
Over current protection trip level		OC	V _D = 15 V, T _j = 125°C	210	300	—	А
Short current protection trip level		SC	V _D = 15 V, T _j = 125°C	315	450	_	А
Over current cut-off time		t _{off (OC)}	V _D = 15 V	—	10	—	μs
Over temperature protection	Trip level	OT	Constanting	111	118	125	°C
	Reset level	OTr	Case temperature	93	100	107	
Control supply under voltage protection	Trip level	UV		11.3 12.0	12.7		
	Reset level	UVr] –	11.8	12.5	13.2	V
Fault output pulse width		t _{FO}	V _D = 15 V	1	2	3	ms

c. Thermal Resistance ($T_j = 25^{\circ}C$)

Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
lunction to case thermal resistance		IGBT	_	—	0.104	°C / W/
	۲۹۲۲ (J-C)	RD —	_	0.25	0/11	
Case to fin thermal resistance	R _{th} (c-f)	Compound is applied		0.05	_	°C / W

Note 1: Switching time test circuit & timing chart



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Package Dimensions: TOSHIBA 2-121A1A

Unit: mm



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